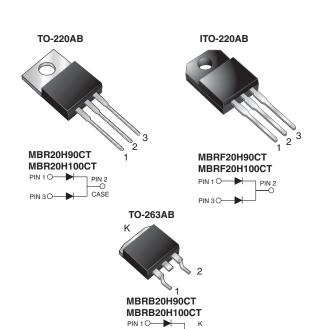
MBR(F,B)20H90CT, MBR(F,B)20H100CT

Vishay General Semiconductor

RoHS

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)} 10 A x 2					
V _{RRM}	90 V to 100 V				
I _{FSM}	250 A				
I _R	4.5 μA				
V _F	0.64				
T _J max.	175 °C				

HEATSINK

FEATURES

- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- · Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H90CT	MBR20H100CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	90	100		
Working peak reverse voltage		V_{RWM}	90	100	V	
Maximum DC blocking voltage		V_{DC}	90	100		
Maximum average forward rectified current	total device	I	20 10			
	per diode	I _{F(AV)}				
eak forward surge current 8.3 ms single half sine-wave uperimposed on rated load		I _{FSM}	250		Α	
Peak repetitive reverse current per diode at $t_p = 2.0 \ \mu s, \ 1 \ kHz$		I _{RRM}	1.0			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range	je	T _J . T _{STG}	- 65 to	o + 175	°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	0.77	- - -	
		I _F = 10 A	T _C = 125 °C	0.64		
		I _F = 20 A	T _C = 25 °C	0.88		
		I _F = 20 A	T _C = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	4.5	μΑ	
			T _J = 125 °C	6.0	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	5.8	2.0	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H100CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	MBRF20H100CT-E3/45	1.99	45	50/tube	Tube	
TO-263AB	MBRB20H100CT-E3/45	1.35	45	50/tube	Tube	
TO-263AB	MBRB20H100CT-E3/81	1.35	81	800/reel	Tape and reel	
TO-220AB	MBR20H100CTHE3/45 (1)	1.85	45	50/tube	Tube	
ITO-220AB	MBRF20H100CTHE3/45 ¹⁾	1.99	45	50/tube	Tube	
TO-263AB	MBRB20H100CTHE3/45 (1)	1.35	45	50/tube	Tube	
TO-263AB	MBRB20H100CTHE3/81 (1)	1.35	81	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

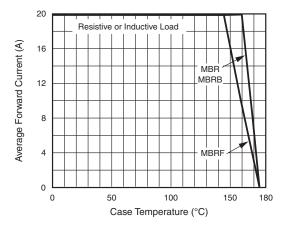


Fig. 1 - Forward Current Derating Curve

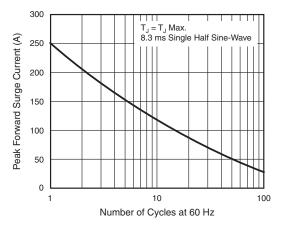


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

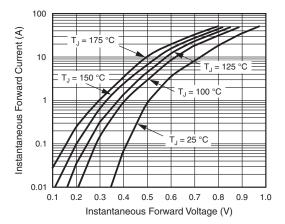


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

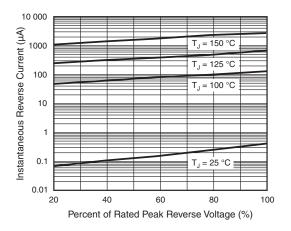


Fig. 4 - Typical Reverse Characteristics Per Diode

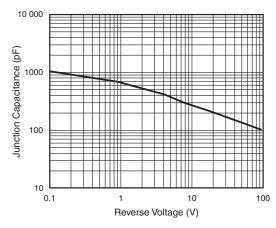


Fig. 5 - Typical Junction Capacitance Per Diode

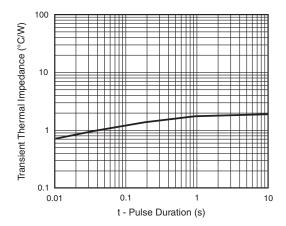


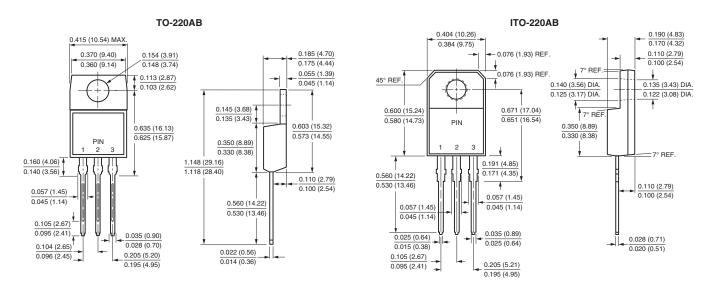
Fig. 6 - Typical Transient Thermal Impedance Per Diode



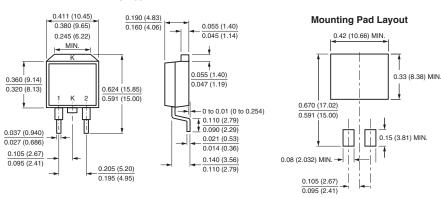
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB





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